

| PART NUMBER               | CAPACITY | I/O VOLTAGE | OPERATING TEMP | BUS WIDTH | PIN COUNT | PART STATUS CODE | COMPONENT CONFIG | FAMILY     | TECHNOLOGY | DRY PACK QTY   | PART TYPE | TAPE & REEL QTY |
|---------------------------|----------|-------------|----------------|-----------|-----------|------------------|------------------|------------|------------|----------------|-----------|-----------------|
| MT29F8G08ADAFWP-AAT:F     | 8Gb      | 3.3 VOLTS   | -40C to +105C  | x8        | 48-pin    | Contact Factory  | 1G x8            | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F2G08ABAEAH4-IT:E     | 2Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 63-ball   | Production       | 256M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F32G08ABAAWP-ITZ:A    | 32Gb     | 3.3 VOLTS   | -40C to +85C   | x8        | 48-pin    | Production       | 4G x8            | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F2G16ABGAH4-AIT:G     | 2Gb      | 1.8 VOLTS   | -40C to +85C   | x16       | 63-ball   | Production       | 128M x16         | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F4G08ABBF4H4-AAT:F    | 4Gb      | 1.8 VOLTS   | -40C to +105C  | x8        | 63-ball   | Contact Factory  | 512M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F128G08AJAAWP-ITZ:A   | 128Gb    | 3.3VOLTS    | -40C to +85C   | x8        | 48-pin    | Production       | 16G x8           | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F2G08ABAEAH4:E        | 2Gb      | 3.3 VOLTS   | 0C to +70C     | x8        | 63-ball   | Production       | 256M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F2G01ABAGD12-AAT:G    | 2Gb      | 3.3 VOLTS   | -40C to +105C  | x1        |           | Contact Factory  | 2G x1            | NAND FLASH | SPI FLASH  | 1122 COMPONENT |           | 1000            |
| MT29F1G08ABBF4H4-AAT:F    | 1Gb      | 1.8 VOLTS   | -40C to +105C  | x8        | 63-ball   | Contact Factory  | 128M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F16G08ABECBM72A3WC1L  | 16Gb     | 3.3 VOLTS   | 0C to +70C     | x8        |           | Contact Factory  | 2G x8            | NAND FLASH | MASS FLASH | DIE            |           |                 |
| MT29F1G08ABBEAM68M3WC1L   | 1Gb      | 3.3VOLTS    | -40C to +70C   | x8        |           | Contact Factory  | 128M x8          | NAND FLASH | MASS FLASH | DIE            |           |                 |
| MT29F16G08ABCCBH1-AAT:C   | 16Gb     | 1.8 VOLTS   | -40C to +105C  | x8        |           | Contact Factory  | 2G x8            | NAND FLASH | MASS FLASH | 1120 COMPONENT |           | 2000            |
| MT29F64G08AFAAWP-ITZ:A    | 64Gb     | 3.3VOLTS    | -40C to +85C   | x8        | 48-pin    | Contact Factory  | 8G x8            | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F4G08ABBF4H4-AIT:F    | 4Gb      | 1.8 VOLTS   | -40C to +85C   | x8        | 63-ball   | Contact Factory  | 512M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F8G08ABACAWP-AIT:C    | 8Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 48-pin    | Contact Factory  | 1G x8            | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F4G08ABADAH4-AITX:D   | 4Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 63-ball   | Contact Factory  | 512M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F4G08ABAEAH4:E        | 4Gb      | 3.3 VOLTS   | 0C to +70C     | x8        | 63-ball   | End of Life      | 512M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F4G08ABADAH4-IT:D     | 4Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 63-ball   | Production       | 512M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F1G08ABAF4H4-AAT:F    | 1Gb      | 3.3 VOLTS   | -40C to +105C  | x8        | 63-ball   | Production       | 128M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F4G08ABAF4H4-AAT:F    | 4Gb      | 3.3 VOLTS   | -40C to +105C  | x8        | 63-ball   | Production       | 512M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F4G08ABAEAH4-ITS:E    | 4Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 63-ball   | End of Life      | 512M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F2G01ABBGD12-AAT:G    | 2Gb      | 1.8 VOLTS   | -40C to +105C  | x1        |           | Production       | 2G x1            | NAND FLASH | SPI FLASH  | 1122 COMPONENT |           | 2500            |
| MT29F1G08ABAEAWP-AITX:E   | 1Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 48-pin    | Production       | 128M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F4G01ABBFD12-AUT:F    | 4Gb      | 1.8 VOLTS   | -40C to +125C  | x1        |           | Production       | 4G x1            | NAND FLASH | SPI FLASH  | 1122 COMPONENT |           |                 |
| MT29F4G08ABBF4H4-IT:F     | 4Gb      | 1.8 VOLTS   | -40C to +85C   | x8        | 63-ball   | Production       | 512M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F16G08ABACAWP-AAT:C   | 16Gb     | 3.3 VOLTS   | -40C to +105C  | x8        | 48-pin    | Production       | 2G x8            | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F4G08ABADAH4:D        | 4Gb      | 3.3 VOLTS   | 0C to +70C     | x8        | 63-ball   | Production       | 512M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F4G08ABADAWP-IT:D     | 4Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 48-pin    | Production       | 512M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F2G01ABAGDWB-IT:G     | 2Gb      | 3.3 VOLTS   | -40C to +85C   | x1        |           | Production       | 2G x1            | NAND FLASH | SPI FLASH  | 1920 COMPONENT |           | 4000            |
| MT29F8G08ABBCAH4-IT:C     | 8Gb      | 1.8 VOLTS   | -40C to +85C   | x8        | 63-ball   | Production       | 1G x8            | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F4G08ABADAWP-AATX:D   | 4Gb      | 3.3 VOLTS   | -40C to +105C  | x8        | 48-pin    | Production       | 512M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F2G01ABBGD12-AUT:G    | 2Gb      | 1.8 VOLTS   | -40C to +125C  | x1        |           | Production       | 2G x1            | NAND FLASH | SPI FLASH  | 1122 COMPONENT |           | 2500            |
| MT29F1G08ABAEAWP-IT:E     | 1Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 48-pin    | Production       | 128M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F2G08ABAGAM79A3WC1L   | 2Gb      | 3.3VOLTS    | 70C            | x8        |           | Production       | 256M x8          | NAND FLASH | MASS FLASH | DIE            |           |                 |
| MT29F2G08ABAGAWP-ITE:G    | 2Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 48-pin    | Contact Factory  | 256M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F1G08ABAFAM78A3WC1L   | 1Gb      | 3.3VOLTS    | -40C to +70C   | x8        |           | Contact Factory  | 128M x8          | NAND FLASH | MASS FLASH | DIE            |           |                 |
| MT29F1G08ABAEAWP-AATX:E   | 1Gb      | 3.3 VOLTS   | -40C to +105C  | x8        | 48-pin    | Contact Factory  | 128M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F2G16ABAGAWP-AIT:G    | 2Gb      | 3.3 VOLTS   | -40C to +85C   | x16       | 48-pin    | Contact Factory  | 128M x16         | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F1G08ABBF4H4-ITE:F    | 1Gb      | 1.8 VOLTS   | -40C to +85C   | x8        | 63-ball   | Contact Factory  | 128M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F2G08ABAEAWP-IT:E     | 2Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 48-pin    | Production       | 256M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F4G08ABAEAWP-IT:E     | 4Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 48-pin    | End of Life      | 512M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F64G08AECABH1-10ITZ:A | 64Gb     | 1.8 VOLTS   | -40C to +85C   | x8        |           | Contact Factory  | 8G x8            | NAND FLASH | MASS FLASH | 1120 COMPONENT |           | 1000            |
| MT29F4G01ABAFD12-AAT:F    | 4Gb      | 3.3 VOLTS   | -40C to +105C  | x1        |           | Production       | 4G x1            | NAND FLASH | SPI FLASH  | 1122 COMPONENT |           | 2000            |
| MT29F2G08ABAEAH4-AITX:E   | 2Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 63-ball   | Production       | 256M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F8G08ADADAH4-IT:D     | 8Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 63-ball   | Production       | 1G x8            | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F4G01ABAFDWB-IT:F     | 4Gb      | 3.3 VOLTS   | -40C to +85C   | x1        |           | Production       | 4G x1            | NAND FLASH | SPI FLASH  | 1920 COMPONENT |           | 2000            |
| MT29F4G08ABADAWP:D        | 4Gb      | 3.3 VOLTS   | 0C to +70C     | x8        | 48-pin    | Production       | 512M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |

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|----------------------------|----------|---------------|----------------|-----------|-----------|------------------|------------------|------------|------------|----------------|-----------|-----------------|
| MT29F2G08ABAEAWP-AITX:E    | 2Gb      | 3.3 VOLTS     | -40C to +85C   | x8        | 48-pin    | Production       | 256M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F2G16ABAEAWP-AIT:E     | 2Gb      | 3.3 VOLTS     | -40C to +85C   | x16       | 48-pin    | Production       | 128M x16         | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F8G08ADAFAH4-AAT:F     | 8Gb      | 3.3 VOLTS     | -40C to +105C  | x8        | 63-ball   | Contact Factory  | 1G x8            | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F2G16ABAGAWP-AAT:G     | 2Gb      | 3.3 VOLTS     | -40C to +105C  | x16       | 48-pin    | Contact Factory  | 128M x16         | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F1G16ABBF4H4-AAT:F     | 1Gb      | 1.8 VOLTS     | -40C to +105C  | x16       | 63-ball   | Production       | 64M x16          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F4G16ABBF4H4-AAT:F     | 4Gb      | 1.8 VOLTS     | -40C to +105C  | x16       | 63-ball   | Production       | 256M x16         | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F2G08ABBEAHC-IT:E      | 2Gb      | 1.8 VOLTS     | -40C to +85C   | x8        | 63-ball   | Production       | 256M x8          | NAND FLASH | MASS FLASH | 1140 COMPONENT |           | 1000            |
| MT29F1G01ABBFDWB-IT:F      | 1Gb      | 1.8 VOLTS     | -40C to +85C   | x1        |           | Production       | 1G x1            | NAND FLASH | SPI FLASH  | 1920 COMPONENT |           | 4000            |
| MT29F2G08ABBG4H4-AAT:G     | 2Gb      | 1.8 VOLTS     | -40C to +105C  | x8        | 63-ball   | Production       | 256M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F4G08ABAD4H4-AATX:D    | 4Gb      | 3.3 VOLTS     | -40C to +105C  | x8        | 63-ball   | Contact Factory  | 512M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F2G08ABAG4H4-IT:G      | 2Gb      | 3.3 VOLTS     | -40C to +85C   | x8        | 63-ball   | Production       | 256M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F4G08ABAFAM70A3WC1     | 4Gb      | 3.3VOLTS      | 70C            | x8        |           | Production       | 512M x8          | NAND FLASH | MASS FLASH | DIE            |           |                 |
| MT29F2G08ABBE4H4-AITX:E    | 2Gb      | 1.8 VOLTS     | -40C to +85C   | x8        | 63-ball   | Production       | 256M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F4G16ABBD4H4-IT:D      | 4Gb      | 1.8 VOLTS     | -40C to +85C   | x16       | 63-ball   | Contact Factory  | 256M x16         | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F32G08ABEABM73A3WC1L   | 32Gb     | 3.3/1.8 VOLTS | 70C            | x8        |           | Contact Factory  | 4G x8            | NAND FLASH | MASS FLASH | DIE            |           |                 |
| MT29F4G08ABAF4WP-IT:F      | 4Gb      | 3.3 VOLTS     | -40C to +85C   | x8        | 48-pin    | Production       | 512M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F2G08ABAG4H4-ITE:G     | 2Gb      | 3.3 VOLTS     | -40C to +85C   | x8        | 63-ball   | Contact Factory  | 256M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F8G01ADAFD12-AAT:F     | 8Gb      | 3.3 VOLTS     | -40C to +105C  | x1        |           | Production       | 8G x1            | NAND FLASH | SPI FLASH  | 1122 COMPONENT |           | 2000            |
| MT29F1G08ABAEAM68M3WC1L    | 1Gb      | 3.3 VOLTS     | 70C            | x8        |           | Contact Factory  | 128M x8          | NAND FLASH | MASS FLASH | DIE            |           |                 |
| MT29F2G08ABAG4WP-AIT:G     | 2Gb      | 3.3 VOLTS     | -40C to +85C   | x8        | 48-pin    | Production       | 256M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F4G01ABBFDWB-IT:F      | 4Gb      | 1.8 VOLTS     | -40C to +85C   | x1        |           | Production       | 4G x1            | NAND FLASH | SPI FLASH  | 1920 COMPONENT |           | 2000            |
| MT29F8G08ABAC4H4-IT:C      | 8Gb      | 3.3 VOLTS     | -40C to +85C   | x8        | 63-ball   | Production       | 1G x8            | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F2G08ABBG4H4-IT:G      | 2Gb      | 1.8 VOLTS     | -40C to +85C   | x8        | 63-ball   | Production       | 256M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F2G16ABBE4H4-AAT:E     | 2Gb      | 1.8 VOLTS     | -40C to +105C  | x16       | 63-ball   | Contact Factory  | 128M x16         | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F2G08ABAG4WP-IT:G      | 2Gb      | 3.3 VOLTS     | -40C to +85C   | x8        | 48-pin    | Production       | 256M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F4G01ABBFD12-AAT:F     | 4Gb      | 1.8 VOLTS     | -40C to +105C  | x1        |           | Production       | 4G x1            | NAND FLASH | SPI FLASH  | 1122 COMPONENT |           | 2000            |
| MT29F2G08ABAG4WP-AAT:G     | 2Gb      | 3.3 VOLTS     | -40C to +105C  | x8        | 48-pin    | Production       | 256M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F1G08ABAE4H4-AATX:E    | 1Gb      | 3.3 VOLTS     | -40C to +105C  | x8        | 63-ball   | Contact Factory  | 128M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F2G01ABBGDM79A3WC1L    | 2Gb      | 1.8VOLTS      | 70C            | x1        |           | Production       | 2G x1            | NAND FLASH | SPI FLASH  | DIE            |           |                 |
| MT29F8G08ABAC4WP-IT:C      | 8Gb      | 3.3 VOLTS     | -40C to +85C   | x8        | 48-pin    | Production       | 1G x8            | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F4G08ABAF4WP-AAT:F     | 4Gb      | 3.3 VOLTS     | -40C to +105C  | x8        | 48-pin    | Contact Factory  | 512M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F1G01ABBFD12-AAT:F     | 1Gb      | 1.8 VOLTS     | -40C to +105C  | x1        |           | Production       | 1G x1            | NAND FLASH | SPI FLASH  | 1122 COMPONENT |           | 2000            |
| MT29F4G08ABBD4H4-IT:D      | 4Gb      | 1.8 VOLTS     | -40C to +85C   | x8        | 63-ball   | Production       | 512M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F4G08ABAD4WP-AITX:D    | 4Gb      | 3.3 VOLTS     | -40C to +85C   | x8        | 48-pin    | Production       | 512M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F2G08ABAG4H4-AIT:G     | 2Gb      | 3.3 VOLTS     | -40C to +85C   | x8        | 63-ball   | Contact Factory  | 256M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F256G08AUCABH3-10ITZ:A | 256Gb    | 1.8 VOLTS     | -40C to +85C   | x8        |           | Production       | 32G x8           | NAND FLASH | MASS FLASH | 1120 COMPONENT |           | 1000            |
| MT29F2G01ABAGDM79A3WC1L    | 2Gb      | 3.3VOLTS      | 70C            | x1        |           | Production       | 2G x1            | NAND FLASH | SPI FLASH  | DIE            |           |                 |
| MT29F1G08ABAE4WP:E         | 1Gb      | 3.3 VOLTS     | 0C to +70C     | x8        | 48-pin    | Production       | 128M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F4G08ABAD4WP-ITX:D     | 4Gb      | 3.3 VOLTS     | -40C to +85C   | x8        | 48-pin    | Production       | 512M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F1G08ABAF4WP-AAT:F     | 1Gb      | 3.3 VOLTS     | -40C to +105C  | x8        | 48-pin    | Contact Factory  | 128M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F2G08ABAE4WP-AATX:E    | 2Gb      | 3.3 VOLTS     | -40C to +105C  | x8        | 48-pin    | Contact Factory  | 256M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F2G08ABAE4WP:E         | 2Gb      | 3.3 VOLTS     | 0C to +70C     | x8        | 48-pin    | Production       | 256M x8          | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F2G01ABBGDWB-IT:G      | 2Gb      | 1.8 VOLTS     | -40C to +85C   | x1        |           | Production       | 2G x1            | NAND FLASH | SPI FLASH  | 1920 COMPONENT |           | 4000            |
| MT29F4G08ABBD4HC-IT:D      | 4Gb      | 1.8 VOLTS     | -40C to +85C   | x8        | 63-ball   | Production       | 512M x8          | NAND FLASH | MASS FLASH | 1140 COMPONENT |           | 1000            |
| MT29F2G08ABBGAM79A3WC1L    | 2Gb      | 1.8 VOLTS     | 70C            | x8        |           | Production       | 256M x8          | NAND FLASH | MASS FLASH | DIE            |           |                 |
| MT29F8G08ABBCAM71M3WC1L    | 8Gb      | 1.8/1.2 VOLTS | 0C to +70C     | x8        |           | Production       | 1G x8            | NAND FLASH | MASS FLASH | DIE            |           |                 |
| MT29F2G08ABAG4H4-AAT:G     | 2Gb      | 3.3 VOLTS     | -40C to +105C  | x8        | 63-ball   | Production       | 256M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |

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|---------------------------|----------|-------------|----------------|-----------|-----------|------------------|------------------|------------|------------|----------------|-----------|-----------------|
| MT29F1G01ABAFDSF-AAT:F    | 1Gb      | 3.3 VOLTS   | -40C to +105C  | x1        |           | Contact Factory  | 1G x1            | NAND FLASH | MASS FLASH | 1440 COMPONENT |           | 1000            |
| MT29F2G08ABBEAH4-IT:E     | 2Gb      | 1.8 VOLTS   | -40C to +85C   | x8        | 63-ball   | Production       | 256M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F4G08ABAFAH4-IT:F     | 4Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 63-ball   | Production       | 512M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 2000            |
| MT29F2G01ABAGD12-AUT:G    | 2Gb      | 3.3 VOLTS   | -40C to +125C  | x1        |           | Production       | 2G x1            | NAND FLASH | SPI FLASH  | 1122 COMPONENT |           | 2500            |
| MT29F8G01ADBFD12-AAT:F    | 8Gb      | 1.8 VOLTS   | -40C to +105C  | x1        |           | Production       | 8G x1            | NAND FLASH | SPI FLASH  | 1122 COMPONENT |           | 2000            |
| MT29F4G08ABBD4H4:D        | 4Gb      | 1.8 VOLTS   | 0C to +70C     | x8        | 63-ball   | Production       | 512M x8          | NAND FLASH | MASS FLASH | 1260 COMPONENT |           | 1000            |
| MT29F1G01ABAFDWB-IT:F     | 1Gb      | 3.3 VOLTS   | -40C to +85C   | x1        |           | Production       | 1G x1            | NAND FLASH | SPI FLASH  | 1920 COMPONENT |           | 4000            |
| MT29F4G08ABBFAM70A3WC1    | 4Gb      | 1.8VOLTS    | 70C            | x8        |           | Production       | 512M x8          | NAND FLASH | MASS FLASH | DIE            |           |                 |
| MT29F4G01ABAFD12-AUT:F    | 4Gb      | 3.3 VOLTS   | -40C to +125C  | x1        |           | Production       | 4G x1            | NAND FLASH | SPI FLASH  | 1122 COMPONENT |           | 2000            |
| MT29F8G08ABACAM71M3WC1L   | 8Gb      | 3.3 VOLTS   | 70C            | x8        |           | Production       | 1G x8            | NAND FLASH | MASS FLASH | DIE            |           |                 |
| MT29F2G16ABBEAHC-AIT:E    | 2Gb      | 1.8 VOLTS   | -40C to +85C   | x16       | 63-ball   | Production       | 128M x16         | NAND FLASH | MASS FLASH | 1140 COMPONENT |           | 1000            |
| MT29F8G08ADAF4WP-AIT:F    | 8Gb      | 3.3 VOLTS   | -40C to +85C   | x8        | 48-pin    | Contact Factory  | 1G x8            | NAND FLASH | MASS FLASH | 960 COMPONENT  |           | 1000            |
| MT29F32G08ABCABH1-10ITZ:A | 32Gb     | 1.8 VOLTS   | -40C to +85C   | x8        |           | Production       | 4G x8            | NAND FLASH | MASS FLASH | 1120 COMPONENT |           | 1000            |